

Technical Description:

The Equipment Under Test (EUT) is a 2.4GHz transceiver for a wireless dongle which operating at 2.403 - 2.479GHz with 1MHz channel spacing. The EUT is powered by a USB port. After the EUT was inserted on PC, The EUT will pair the corresponding wireless keyboard for wireless data transfer.

Operating Frequency Band: 2.403GHz ~ 2.479GHz
Modulation Method: GFSK.

The functions of main ICs are mentioned as below.

- 1) U1 acts as 2.4GHz RF transceiver
- 2) U2 acts as USB Controller.
- 3) U3 acts as EEPROM.



DATA SHEET

EM198810AW

2.4 GHz ISM Band Transceiver/Framer IC
(QFN24 4x4x0.8mm package)

Production Data Sheet

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CONTENTS

1. Features
2. Block Diagram
3. Pins/pads name and pins/pads location
 - 3.1 Pins name
 - 3.2 Package outline
 - 3.3 Order information
4. Digital Base Band Interface
 - 4.1 SPI Command Format
 - 4.2 Register Information
 - 4.2.1 Package type define and FIFO point set**
 - 4.2.2 Digital Interface**
 - 4.2.3 Typical Register Values**
 - 4.2.4 State Diagram**
5. Electrical Characteristics
6. Application Reference Design
7. Soldering

2.4 GHz ISM BAND TRANSCEIVER/FRAMER IC

1. FEATURES

The EM198810 is a CMOS integrated circuit that performs all functions from the antenna to the microcontroller for transmission and reception of a 2.4GHz digital data. This transceiver IC integrates most of the functions required for data transmission into a single integrated circuit. Additionally, the programmability implemented reduces significantly external components count, board space requirements and external adjustments.

Key Features:

- Combines 2.4 GHz GFSK RF transceiver with 8-bit data framer function
- Eliminates need for external software or hardware FIFO; offloads MCU for other tasks
- Simple microprocessor interface – 4 wires for SPI, plus 3 wires for RST/buffer control
- Each transmit, receive buffer is 64 bytes deep
- Long packets are possible if buffers are read/written before overflow/underflow occurs
- Always 1Mbps over-the-air symbol rate, regardless of MCU speed or architecture
- Preamble can be 1 to 8 bytes
- Supports 1, 2, 3, or 4 word address (up to 64 bits)
- Various Payload data formats to eliminate DC offset, enhance receive clock recovery and BER
- Programmable data whitening
- Supports Forward Error Correction (FEC): none, 1/3, or 2/3
- Supports 16-bit CRC
- Baseband output clock available
- Power management for minimizing current consumption
- 5x5mm QFN package with minimum RF parasitic
- Lead-free packaging and dice is available on request

Applications

- Wireless devices that need quick time-to-market
- Simple and fast wireless data networks
- Cordless headsets and Cellular Phones
- Wireless streaming audio
- Wireless voice and VOIP
- Wireless Skype earphone
- Home and factory automation
- Wireless security and access control
- Battery Powered wireless devices

1.1 Description

The Elan EM198810 IC is a low-cost, fully integrated CMOS radio frequency (RF) transceiver block, combined with a 64-byte buffered framer block. The RF transceiver block is a self-contained, fast-hopping GFSK data modem, optimised for use in the widely available 2.4 GHz ISM band. It contains transmit, receive, VCO and PLL functions, including an on-chip channel filter and resonator, thus minimizing the need for external components. The receiver utilizes extensive digital processing for excellent overall performance, even in the presence of interference and transmitter impairments. Transmit power is digitally controlled. The low-IF receiver architecture results in sensitivity to -80dBm or better, with impressive selectivity.

In normal applications, the EM198810 is connected to a low cost microcontroller(ex:EM78P451S).

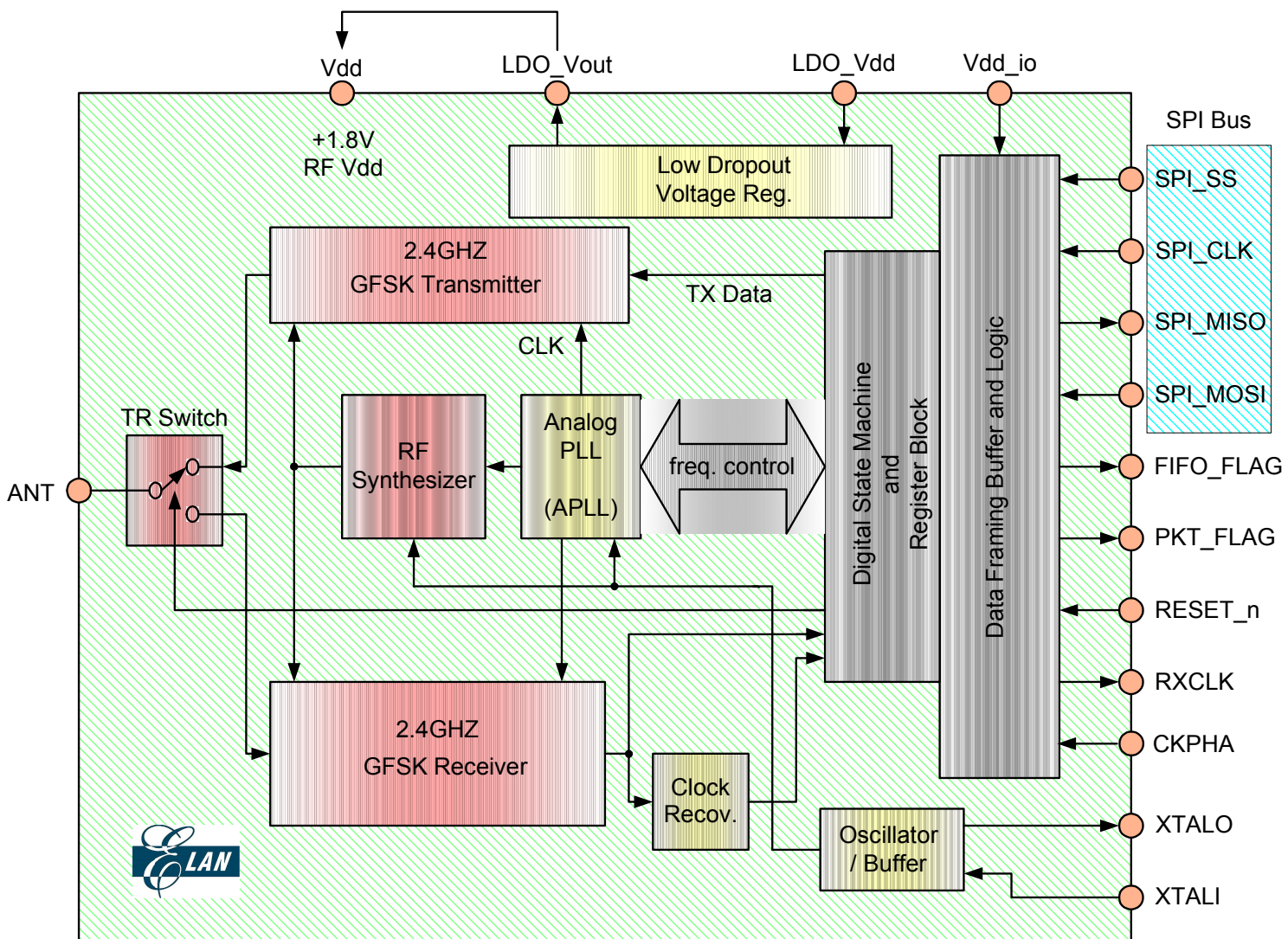
In normal application The on-chip framer processes and stores the RF data in the background, unloading this critical timing function from the MCU. This lowers MCU speed requirements, expedites product development time, and frees the MCU for implementing additional product features.

The framer register settings determine the over-the-air formatting characteristics. Many configurations are possible, depending on the user's specific needs. Raw transmit data is easily sent over-the-air as a complete frame of data, with preamble, address, payload, and CRC. Receiving data is just the opposite, using the preamble to train the receiver clock recovery, then the address is checked, then the data is reverse formatted for receive, followed by CRC. All of this is done in hardware to ease the programming and overhead requirements of the baseband MCU.

For longer battery life, power consumption is minimized by automatic enabling of the various transmit, receive, PLL, and PA sections, depending on the instantaneous state of the chip. A sleep mode is also provided for ultra low current consumption.

This product is available in 32-lead 5x5 mm JEDEC standard QFN package, featuring an exposed pad on the bottom for best RF characteristics. Lead-free RoHS compliant packaging is available on request.

2. Block diagram



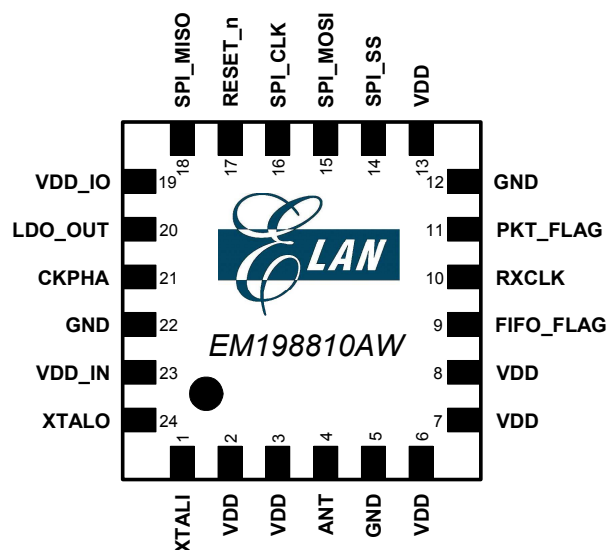
- Fig. 1 -

3. Pins names and pins location

3.1 Pins names

| SYMBOL | Type | PIN | DESCRIPTION |
|-----------|----------------|-------------|---|
| XTALI | AI | 1 | Input to the crystal oscillator gain block. |
| VDD | PWR | 2 | Power supply voltage(+1.8V). |
| VDD | PWR | 3 | Power supply voltage(+1.8V). |
| ANT | 50 Ω RF | 4 | RF input/output. |
| GND | GND | 5 | Ground connection. |
| VDD | PWR | 6 | Power supply voltage(+1.8V). |
| VDD | PWR | 7 | Power supply voltage(+1.8V). |
| NC | PWR | 8 | Power supply voltage(+1.8V). |
| FIFO_FLAG | O | 9 | FIFO full/empty flag. |
| RXCLK | O | 10 | Receiver symbol timing clock recovery output. Fixed at 1MHz fundamental rate. |
| PKT_FLAG | O | 11 | Transmit/Receive packet process flag. |
| GND | GND | 12 | Ground connection. |
| VDD | PWR | 13 | Power supply voltage(+1.8V). |
| SPI_SS | I | 14 | Enable line for the SPI bus. Active low. |
| SPI_MOSI | I | 15 | Data input for the SPI bus. |
| SPI_CLK | I | 16 | Clock line for the SPI bus. |
| RESET_n | I | 17 | When RESET_n is low, most of the chip shuts down to conserve power. When raised high, RESET_n is used to turn on the chip, restoring all registers to their default value. |
| SPI_MISO | O | 18 | Data output for the SPI bus. |
| VDD_IN | PWR | 19 | Vdd for the digital i/o pins, plus the on-chip LDO. Nominally +3.3 VDC. |
| LDO_OUT | PWR | 20 | +1.8V output of the on-chip LDO voltage regulator. |
| CKPHA | DI | 21 | SPI clock phase. When 0, SPI_MOSI data clocked in on rising edge of SPI_CLK. When 1, SPI_MOSI data clocked in on falling edge of SPI_CLK. |
| GND | GND | 22 | Ground connection. |
| VDD | PWR | 23 | Power supply voltage(+1.8V). |
| XTALO | AO | 24 | Output of the crystal oscillator gain block. |
| GND | GND | Exposed pad | Ground connection. |

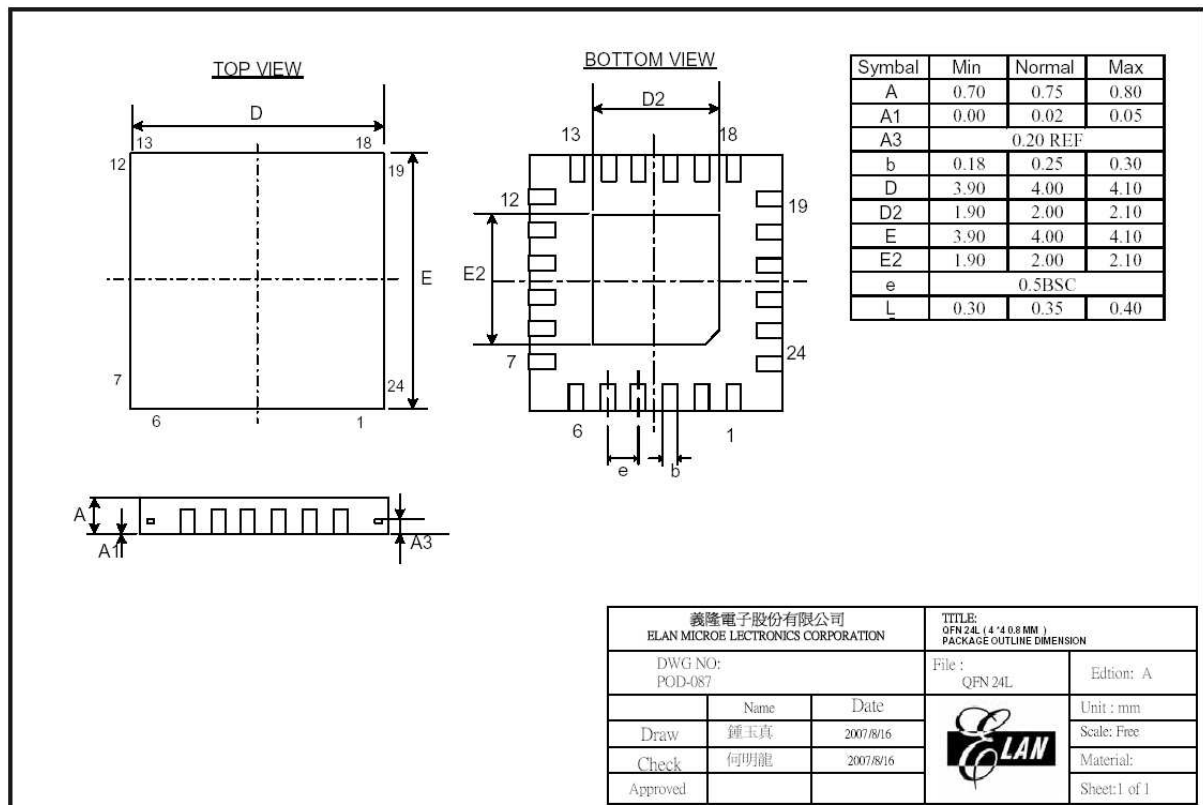
- Table 1 -



- Figure 2 -

3.2 Package Outline

QFN24 Lead Exposed Pad Package, 4x4 mm Pkg.



- Table 2 -

3.3 Order information

| Type number | Package | |
|-------------|---------|---|
| | Name | Description |
| EM198810AW | QFN24 | Plastic, quad flat package; no leads; 24 terminals; body 4 x 4 x 0.8 mm |

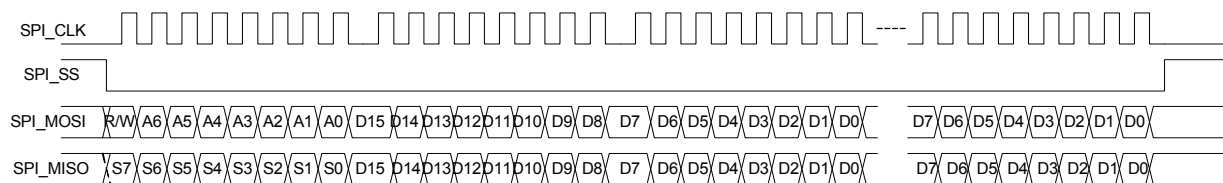
4 Digital Base Band Interface

4.1 SPI Command Format

The SPI interface is used to program the IC via the 4 pins SPI_CLK, SPI_SS, SPI_MOSI and SPI_MISO. The SPI_MOSI and SPI_CLK pins are used to load data into an internal shift register. The SPI_MOSI and SPI_CLK pins are used to send data to microcontroller. The data are loaded into the shift register and sent to microcontroller on the falling edge of the clock SPI_CLK and latched on the rising edge of the SPI_SS signal. When the SPI_SS pin is high, the data stored in the shift register is retained even if a SPI_CLK is applied. When the SPI_SS pin is low the data can be rewritten and resent. Inputs timing of the SPI_CLK, SPI_SS, SPI_MOSI and SPI_MISO are shown in the Fig.3.

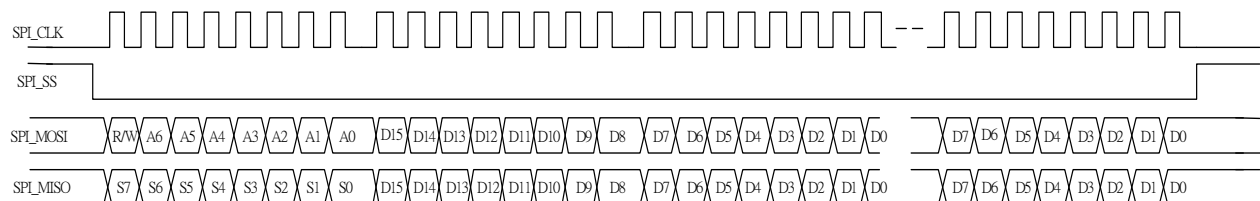
Format 1

CKPHA = 0:



Format 2

CKPHA = 1:



- Fig. 3 -

4.2 Register Information

4.2.1 Package type define and FIFO point set

| preamble | SYNC | trailer | payload | CRC |
|----------|------|---------|---------|-----|
|----------|------|---------|---------|-----|

↑
Automatically set FIFO write_point=0
when RX received SYNC
Automatically set FIFO read_point=0
when RX received SYNC or after transmit SYNC when TX

- Figure 4 -

- * Preamble: 1 ~ 8 bytes programmable
- * SYNC: 32/48/64 bits programmable as device syncword
- * Trailer: 4~16 bits programmable
- * Payload: TX/RX data, there are 4 data types: raw data, 8_10 bits, Manchester, interleave , with FEC option
- * CRC: 16 bit CRC is option

Note: For transmit, it is needed to clear FIFO write point before application write in data via access reg82[15].

4.2.2 Digital Interface

It is very simple interface with application, consisting of SPI interface plus two handshake signals (Table 3).

The EM198810 SPI can only support slave mode.

| Pin | Description |
|-----------|-------------------------|
| SPI_CLK | SPI clock input |
| SPI_SS | SPI slave select input |
| SPI_MOSI | SPI data in |
| SPI_MISO | SPI data out |
| PKT_FLAG | Packet TX/RX flag |
| FIFO_FLAG | FIFO full/empty |
| RESET_n | Reset input, active low |

- Table 3 -

4.2.3 Typical Register Values

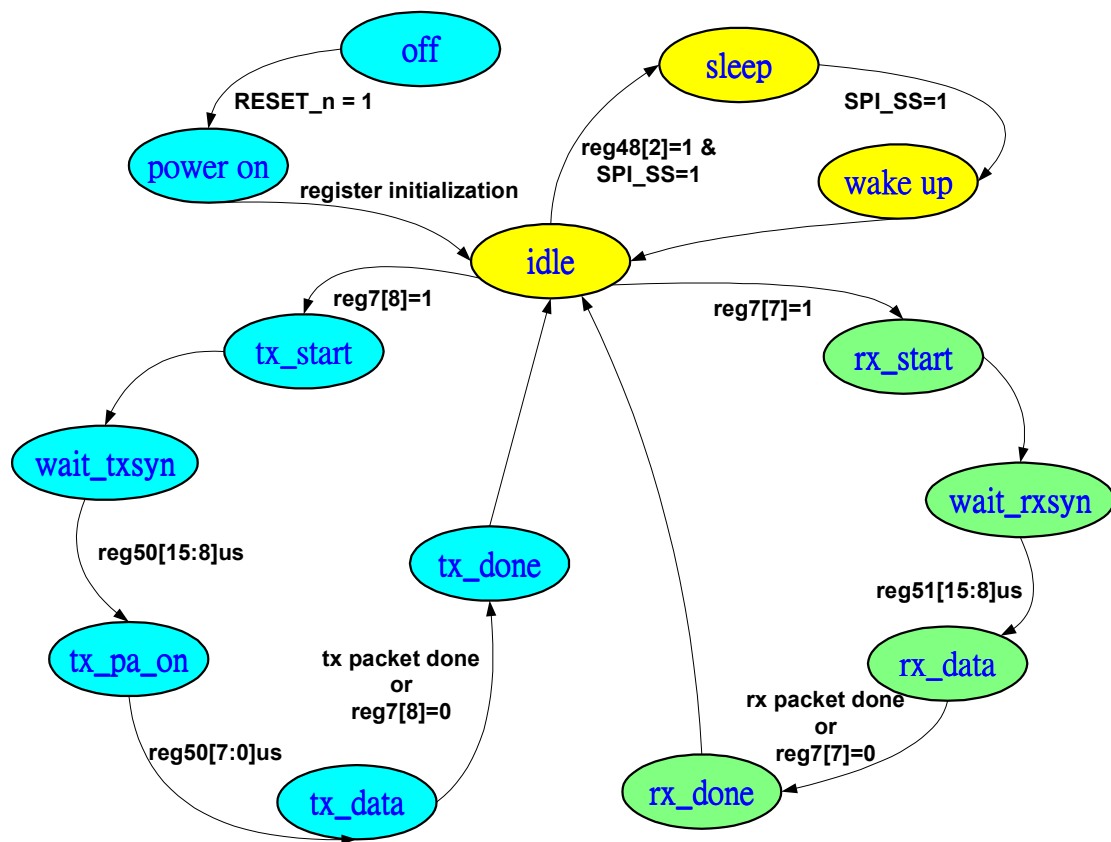
EM198810AW recommended setting table (Table 4).

| Reg. address | Read/Write | Default value (Hexadecimal) | Recommend value (12MHz crystal frequency) (Hexadecimal) |
|--------------|------------|-----------------------------|---|
| 0 | R/W | 0000 | CD51 |
| 2 | R/W | 00C1 | 0061 |
| 4 | R/W | 0688 | 3CD0 |
| 5 | R/W | 0041 | 00A1 |
| 9 | R/W | 0003 | 3003 |
| 14 | R/W | 6617 | 6697 |
| 16 | R/W | 0000 | F000 |
| 18 | R/W | FC00 | E000 |
| 19 | R/W | 0014 | 2114 |
| 20 | R/W | 8103 | 819C |
| 21 | R/W | 0962 | 6962 |
| 22 | R/W | 2602 | 0402 |
| 23 | R/W | 2602 | 0802 |
| 24 | R/W | 30C0 | B080 |
| 25 | R/W | 3814 | 7819 |
| 26 | R/W | 5304 | 6704 |
| 48 | R/W | 1800 | 5800 |
| 51 | R/W | 4000 | A000 |
| 56 | R/W | 4407 | 4407 |
| 57 | R/W | B000 | E000* |

- Table 4 -

For the latest register value recommendations, please contact Elan Microelectronics technical group.

4.2.4 State Diagram



- Figure 5 -

5. Electrical Characteristics

5.1 Absolute Maximum Rating

| Parameter | Symbol | Rating | | | Unit |
|---|-----------------------|--------|------|------|------|
| | | Min. | Typ. | Max. | |
| Operating Temp. | T _{OP} | -40 | | +85 | °C |
| Storage Temp. | T _{STORAGE} | -55 | | +125 | °C |
| VDD_IO Supply Voltage | V _{DDIO_MAX} | | | +3.7 | VDC |
| VDD Supply Voltage | V _{DD_MAX} | | | +2.5 | VDC |
| Applied Voltages to Other Pins | V _{OTHER} | -0.3 | | +3.7 | VDC |
| Input RF Level | P _{IN} | | | +10 | dBm |
| Output Load mismatch (Z ₀ =50 ohm) | VSWR _{OUT} | | | 10:1 | VSWR |

- Table 5 -

Note: 1. Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Recommended operating conditions indicate conditions for which the device is intended to be functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions, see the Electrical Characteristics section below.

2. These devices are electro-static sensitive. Devices should be transported and stored in anti-static containers. Equipment and personnel contacting the devices need to be properly grounded. Cover workbenches with grounded conductive mats.

5.2 Characteristics

The following specifications are guaranteed for T_A=25°C, V_{DD}=1.80±0.18VDC, unless otherwise noted:

| Parameter | Symbol | Specification | | | Unit | Test Condition and Notes |
|---|------------------------|---------------------------|------|---------------------------|------|---|
| | | Min. | Typ. | Max. | | |
| Current Consumption | | | | | | |
| Current Consumption - TX | I _{DD_TX} | | 27 | | mA | P _{OUT} = nominal output power |
| Current Consumption - RX | I _{DD_RX} | | 25 | | mA | |
| Current Consumption – DEEP IDLE | I _{DD_D_IDLE} | | 1.9 | | mA | RF Synthesizer and VCO: OFF (see Reg. 21) |
| Current Consumption – SLEEP | I _{DD_SLP} | | 8.5 | | uA | |
| Digital Inputs | | | | | | |
| Logic input high | V _{IH} | 0.8 V _{DD_IN} | | 1.2 V _{DD_IN} | V | |
| Logic input low | V _{IL} | 0 | | 0.8 | V | |
| Input Capacitance | C _{IN} | | | 10 | pF | |
| Input Leakage Current | I _{LEAK_IN} | | | 10 | uA | |
| Digital Outputs | | | | | | |
| Logic output high | V _{OH} | 0.8 V _{DD_IN} | | V _{DD_IN} | V | |
| Logic output low | V _{OL} | | | 0.4 | V | |
| Output Capacitance | C _{OUT} | | | 10 | pF | |
| Output Leakage Current | I _{LEAK_OUT} | | | 10 | uA | |
| Rise/Fall Time | T _{RISE_OUT} | | | 5 | nS | |
| Clock Signals | | | | | | |
| SPI_CLK rise, fall time | T _{r_spi} | | | 25 | nS | Requirement for error-free register reading, writing. |
| SPI_CLK frequency range | F _{SPI} | 0 | 12 | | MHz | |
| Overall Transceiver | | | | | | |
| Operating Frequency Range | F _{OP} | 2400 | | 2482 | MHz | |
| Antenna port mismatch (Z ₀ =50Ω) | VSWR _I | | <2:1 | | VSWR | Receive mode. |
| | VSWR _O | | <2:1 | | VSWR | Transmit mode. |

| | | | | | | | |
|--|--------------------------|--------------------|------|------|--------|---|---|
| Receive Section: @ BER ≤ 0.1% | | | | | | | |
| Receiver sensitivity | | | -85 | -80 | dBm | Meas. at antenna pin. | |
| Maximum useable signal | | -20 | +5 | | dBm | | |
| Data (Symbol) rate | T _s | | 1 | | uS | | |
| Min. Carrier/Interference ratio: @ BER ≤ 0.1% | | | | | | | |
| Co-Channel Interference | CI _{_cochannel} | | +9 | | dB | -60 dBm desired signal. | |
| Adjacent Ch. Interference, 1MHz offset | CI _{_1} | | +6 | | dB | -60 dBm desired signal. | |
| Adjacent Ch. Interference, 2MHz offset | CI _{_2} | | -12 | | dB | -60 dBm desired signal. | |
| Adjacent Ch. Interference, ≥ 3MHz offset | CI _{_3} | | -24 | | dB | -67 dBm desired signal. | |
| Out-of-Band Blocking | OBB _{_1} | -10 | | | dBm | 30 MHz to 2000 MHz | Meas. with ACX BF2520 ceramic filter on ant. pin. Desired sig.-70dBm. |
| | OBB _{_2} | -27 | | | dBm | 2000 MHz to 2400 MHz | |
| | OBB _{_3} | -27 | | | dBm | 2500 MHz to 3000 MHz | |
| | OBB _{_4} | -10 | | | dBm | 3000 MHz to 12.75 GHz | |
| Transmit Section: Reg. 9, bits 15-8 set to 00000000 | | | | | | | |
| RF Output Power | P _{AV} | | | +2 | dBm | Power Level 0 (Max. power setting). | |
| Second Harmonic | | | -25 | | dBm | Conducted to ANT pin. | |
| Third Harmonic | | | -50 | | dBm | Conducted to ANT pin. | |
| Modulation Characteristics | | | | | | | |
| Peak FM Demodulation. | 00001111 pattern | △f _{1avg} | | 280 | KHz | | |
| | 01010101 pattern | △f _{2max} | | 225 | KHz | | |
| In-Band Spurious Emission | | | | | | | |
| 2MHz offset | IBS _{_2} | | | -40 | dBm | | |
| >3MHz offset | IBS _{_3} | | | -60 | dBm | | |
| Out-of-Band Spurious Emission | | | | | | | |
| Operation | OBS_O_1 | | | -36 | dBm | 30 MHz ~ 1 GHz | |
| | OBS_O_2 | | -45 | -30 | dBm | 1 GHz ~ 12.75 GHz, excludes desired signal. | |
| | OBS_O_3 | | <-60 | -47 | dBm | 1.8 GHz ~ 1.9 GHz | |
| | OBS_O_4 | | <-65 | -47 | dBm | 5.15 GHz ~ 5.3 GHz | |
| RF VCO and PLL Section | | | | | | | |
| Typical PLL lock range | F _{LOCK} | 2366 | | 2516 | MHz | | |
| TX, RX Frequency Tolerance | | | -- | | ppm | Same as XTAL pins frequency tolerance | |
| Channel (Step) Size | | | 1 | | MHz | | |
| SSB Phase Noise | | | -95 | | dBc/Hz | 550KHz offset | |
| | | | -115 | | dBc/Hz | 2MHz offset | |
| Crystal oscillator freq. range (Reference Frequency) | | | 12 | | MHz | Designed for 12 MHz crystal reference freq. | |
| Crystal oscillator digital trim range, typ. | | -5 | | +5 | ppm | | |
| RF PLL Settling Time | T _{HOP} | | 75 | 150 | uS | Settle to within 30KHz of final value | |
| Spurious Emissions | OBS _{_1} | | <-75 | -57 | dBm | 30 MHz ~ 1 GHz | IDLE state, Synthesizer and VCO ON. |
| | OBS _{_2} | | -68 | -47 | dBm | 1 GHz ~ 12.75 GHz | |
| LDO Voltage Regulator Section | | | | | | | |
| Dropout Voltage | V _{do} | | | 0.5 | V | Measured during Receive state | |
| Quiescent current | I _q | | 8 | | uA | No-load current consumed by LDO reg. | |

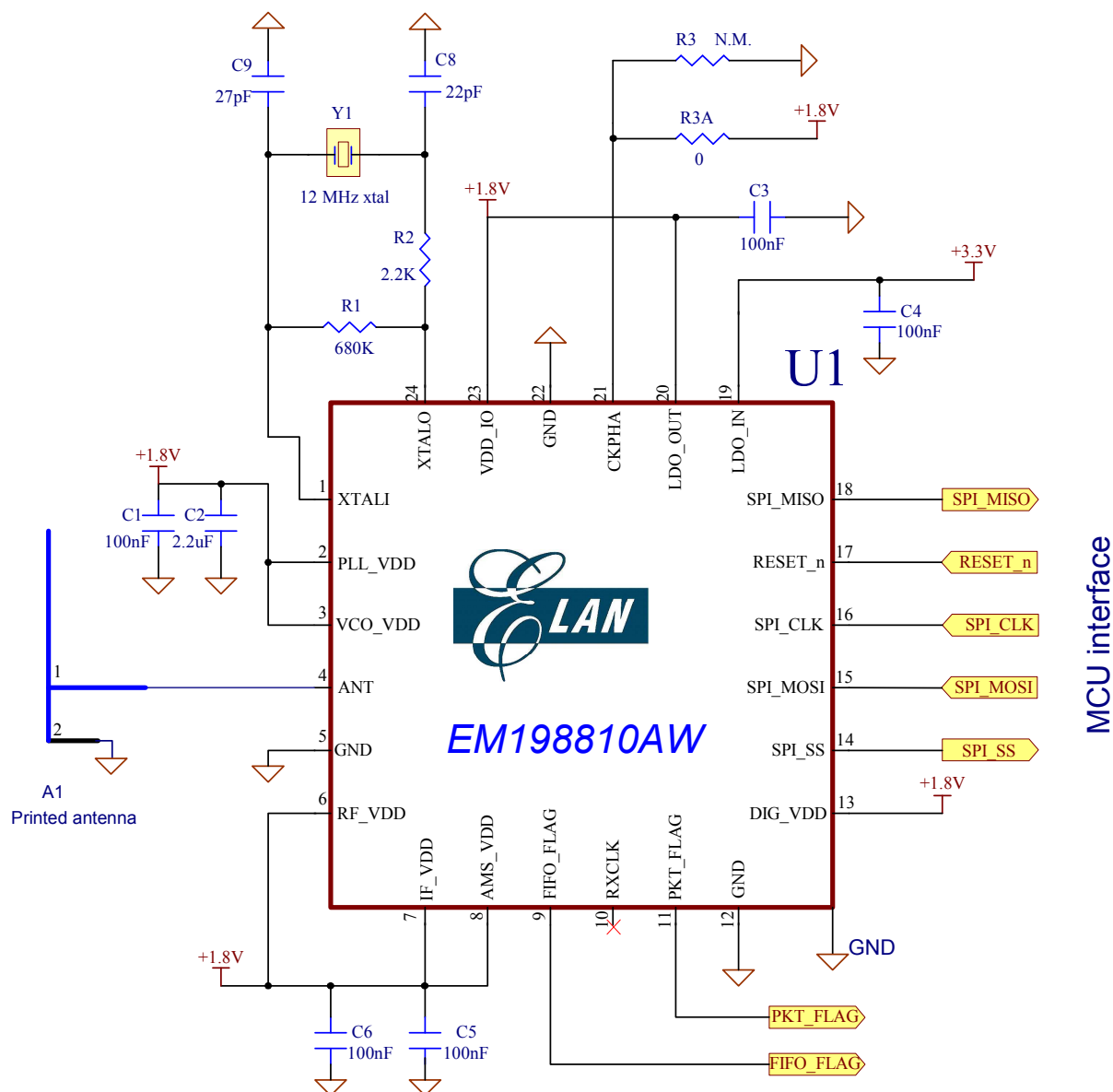
- Table 6 -

6. Application Circuit

Typical Application

Note: Different crystals or layout changes may require different R/C values.

Note 1: Jumper CKPHA pin 21 to +1.8V or GND to set SPI clock phase as desired.



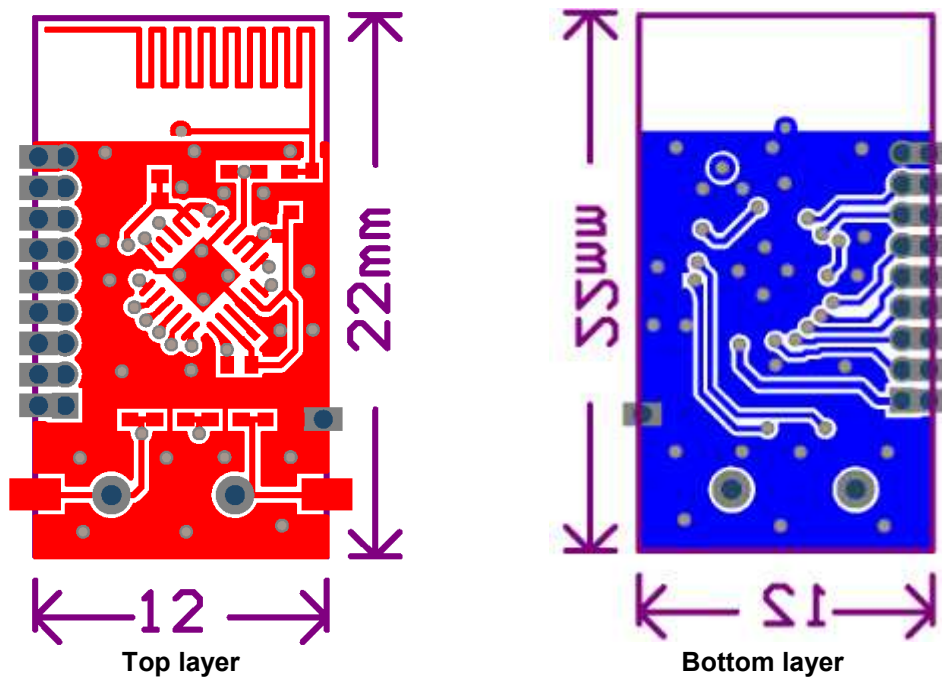
- Figure 6 -

BOM list

| Comment | Description | Designator | Quantity | Footprint |
|------------|-------------|----------------|----------|------------|
| 22pF* | Capacitor | C8 | 1 | SMD-0603 |
| 27pF* | Capacitor | C9 | 1 | SMD-0603 |
| 100nF | Capacitor | C1 C3 C4 C5 C6 | 5 | SMD-0603 |
| 2.2uF | Capacitor | C2 | 1 | SMD-0603 |
| 0 ohm | Resistor | R3A | 1 | SMD-0603 |
| 2.2k | Resistor | R2 | 1 | SMD-0603 |
| 680k | Resistor | R1 | 1 | SMD-0603 |
| 12MHz | Crystal | Y1 | 1 | OSC 5x3.2 |
| EM198810AW | IC | U1 | 1 | QFN 24 4x4 |

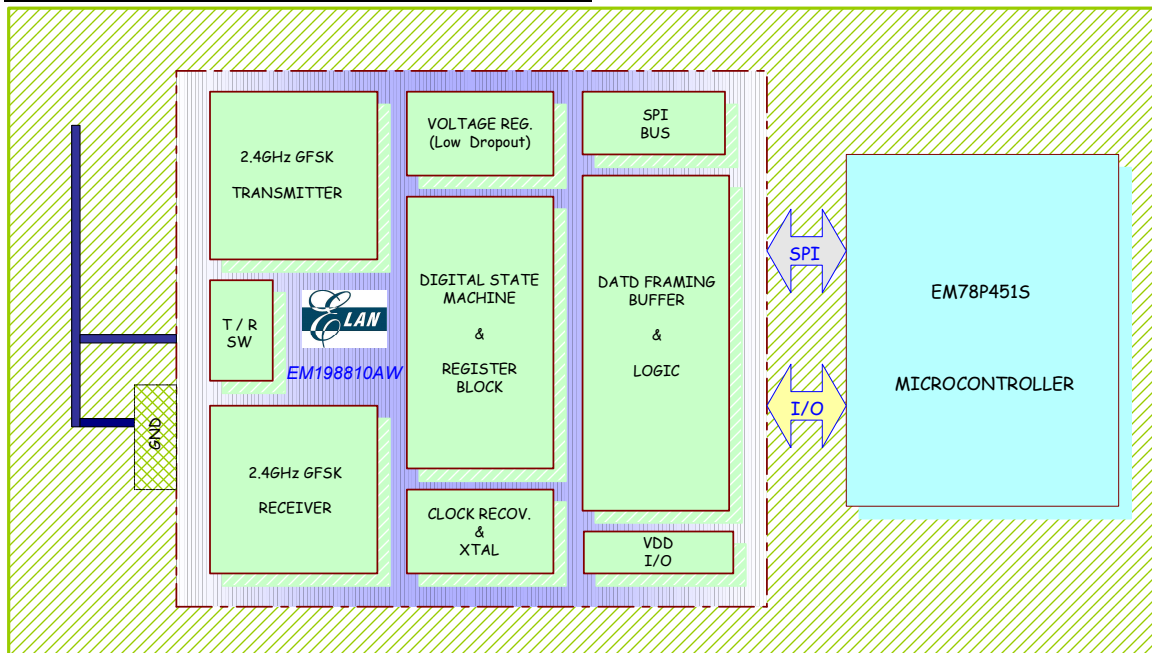
- Table 7 -

PCB layout



- Figure 7 -

Wireless Personal Area Network Solution



Elan Wireless personal area network Total Solution

- Fig. 8 -

7. SOLDERING

Reflow soldering requires paste to be applied to the printed-circuit board by screen printing, stencilling or pressure-syringe dispensing before package placement. Several methods exist for reflowing, throughput times vary between 100 and 300 seconds depending on heating method.

Recommendation: Follow IPC/JEDEC J-STD-020B

Condition: Average ramp-up rate (183°C to peak): 3°C/sec. max.

Preheat: 100 ~ 150°C 60 ~ 120 sec.

Temperature maintained above 183°C: 60 ~ 150sec.

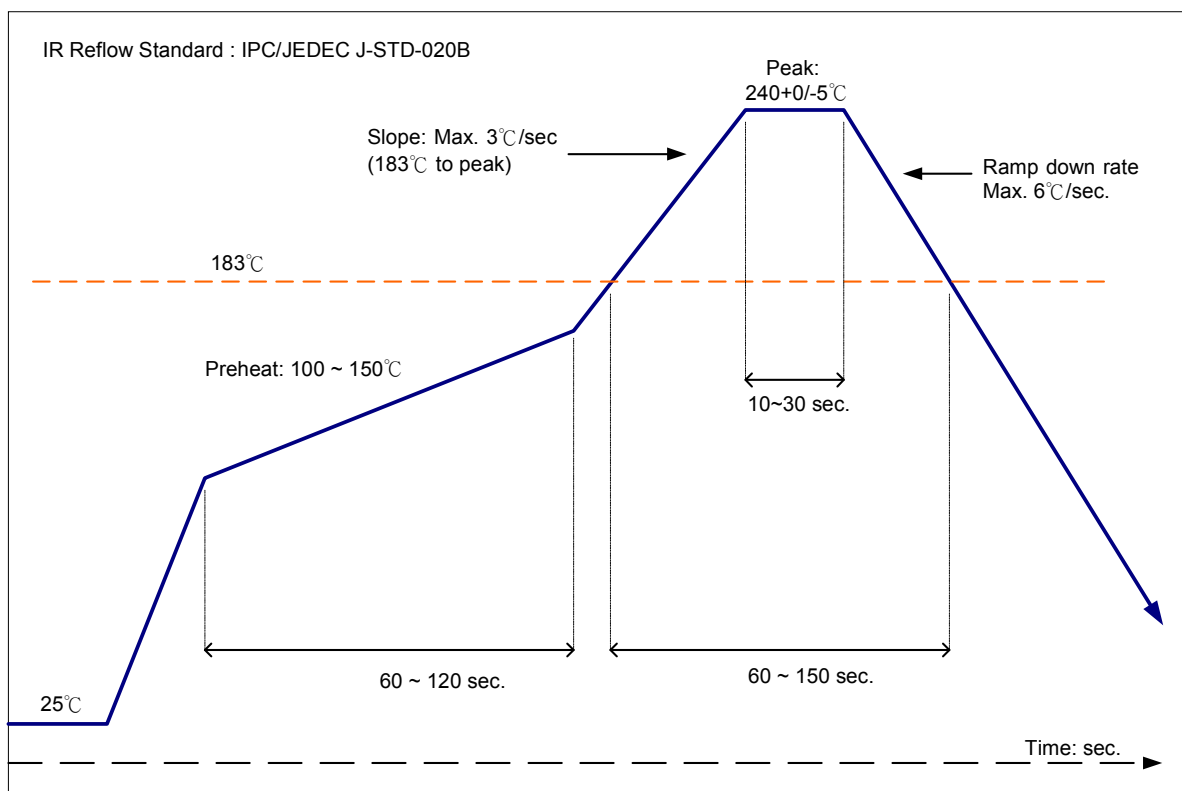
Time within 5°C of actual peak temperature: 10 ~ 30sec.

Peak temperature: 240+0/-5°C

Ramp-down rate: 6°C/sec. max.

Time 25°C to peak temperature: 6 minutes max.

Cycle interval: 5 minutes



- Fig. 9 -

DATA SHEET STATUS

| Data Sheet Status | Product Status | Definitions |
|---------------------------|----------------|--|
| Objective specification | Development | This data sheet contains data from the objective specification for product development. Elan Microelectronics reserves the right to change the specification in any manner without notice. |
| Preliminary specification | Qualification | This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Elan Microelectronics reserves the right to change the specification without notice in order to improve the design and supply the best possible product. |
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